

Role of thermalizing and nonthermalizing walls in phonon heat conduction along thin films

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Phonon boundary scattering is typically treated using the Fuchs-Sondheimer theory, which assumes that phonons are thermalized to the local temperature at the boundary. However, whether such a thermalization process actually occurs and its effect on thermal transport remains unclear. Here we examine thermal transport along thin films with both thermalizing and nonthermalizing walls by solving the spectral Boltzmann transport equation for steady state and transient transport. We find that in steady state, the thermal transport is governed by the Fuchs-Sondheimer theory and is insensitive to whether the boundaries are thermalizing or not. In contrast, under transient conditions, the thermal decay rates are significantly different for thermalizing and nonthermalizing walls. We also show that, for transient transport, the thermalizing boundary condition is unphysical due to violation of heat flux conservation at the boundaries. Our results provide insights into the boundary scattering process of thermal phonons over a range of heating length scales that are useful for interpreting thermal measurements on nanostructures.

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I. INTRODUCTION

Engineering the thermal conductivity of nanoscale materials has been a topic of considerable research interest over the past two decades [1]. While applications such as GaN transistors [2,3] and light emitting diodes (LEDs) [4] require high thermal conductivity substrates to dissipate heat, the performance of thermoelectric and thermal insulation devices can be significantly enhanced by reducing their thermal conductivity [5,6]. In many of these applications, phonon boundary scattering is the dominant resistance to heat flow, making the detailed understanding of this process essential for advancing applications.

Phonon boundary scattering has been studied extensively both theoretically and experimentally. The thermal conductivity reduction due to boundary scattering of phonons is conventionally treated using the Fuchs-Sondheimer theory, which was first derived for electron boundary scattering independently by Fuchs [7] and Reuter and Sondheimer [8] and was later extended to phonon boundary scattering in several works [9–11]. Fuchs-Sondheimer theory is widely used to interpret experiments but makes an important assumption that the diffusely scattered part of the phonon spectrum at a partially specular wall is at a local thermal equilibrium with the wall—the thermalizing boundary condition. The thermalizing boundary condition is also a key assumption in the diffuse boundary scattering limit of Casimir’s theory [12].

Several computational works [11,13–16] have studied the reduction in thermal conductivity due to phonon boundary scattering in nanostructures by solving the phonon Boltzmann transport equation (BTE). These works have considered either thermalizing or nonthermalizing boundaries but have never compared the effect of these two different boundary conditions on the thermal conductivity of nanostructures. Several experimental works have also studied the reduction in thermal conductivity of nanomaterials such as nanowires [17–19], thin films [10,20,21], and nanopatterned structures [22] due to phonon boundary scattering. These works have used the Fuchs-

Sondheimer theory to interpret their measurements. However, it is not clear whether the assumptions made in the Fuchs-Sondheimer theory are necessarily applicable for these experiments. In fact, an analysis of the effect of the key assumption made in the Fuchs-Sondheimer theory, that the walls are thermalizing, has never been investigated due to the challenges involved in solving the BTE for nonthermalizing walls.

Here, we examine the role of thermalizing and nonthermalizing walls in heat conduction along thin films by solving the spectral phonon BTE for a suspended thin film under steady state and transient transport conditions. We find that steady state transport is insensitive to whether phonons are thermalized or not at the boundaries and that the Fuchs-Sondheimer theory accurately describes thermal transport along the thin film. In the case of transient transport, we find that the decay rates of the initial temperature distribution [defined by $\gamma = 4\pi^2 k_{\text{eff}} / (C\lambda^2)$, where C is the volumetric specific heat of the material and k_{eff} is the effective thermal conductivity of the thin film at a heating length scale $\lambda/2$] are significantly different for thermalizing and nonthermalizing walls, and that the Fuchs-Sondheimer theory accurately predicts the thermal conductivity only when the thermal transport is diffusive. Moreover, under transient transport conditions, we find that phonons cannot undergo thermalization at the boundaries in general due to the violation of heat flux conservation. Our results provide insights into the boundary scattering process of thermal phonons that are useful for interpreting thermal measurements on nanostructures.

II. MODELING

A. Boltzmann transport equation

We begin our analysis by considering the two-dimensional spectral transient BTE under the relaxation time approximation for an isotropic crystal, given by

$$\begin{aligned} \frac{\partial g_\omega}{\partial t} + \mu v_\omega \frac{\partial g_\omega}{\partial z} + v_\omega \sqrt{1 - \mu^2} \cos \phi \frac{\partial g_\omega}{\partial x} \\ = -\frac{g_\omega - g_o(T)}{\tau_\omega} + \frac{Q_\omega}{4\pi}. \end{aligned} \quad (1)$$

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Here, g_ω is the phonon energy distribution function, ω is the phonon frequency, v_ω is the phonon group velocity, τ_ω is the phonon relaxation time, x and z are the spatial coordinates, t is the time variable, $g_0(T)$ is the equilibrium phonon distribution function at a deviational temperature $T = T_0 + \Delta T$ from an equilibrium temperature T_0 , μ is the direction cosine, ϕ is the azimuthal angle, and Q_ω is the rate of volumetric heat generation for each phonon mode. As the in-plane (x)

direction is infinite in extent, we require boundary conditions only for the cross-plane (z) direction. In the traditional Fuchs-Sondheimer problem, the boundary conditions enforce that the diffusely scattered phonons are thermalized while also allowing some phonons to be specularly reflected. Here, we generalize these boundary conditions to allow for the possibility of both partial thermalization and partial specularly as

for $\mu \in (0, 1]$,

$$g_\omega^+(0, \mu, \phi) = p_\omega g_\omega^-(0, -\mu, \phi) + (1 - p_\omega) \left(\sigma_\omega \frac{C_\omega \Delta T(z=0)}{4\pi} - \frac{(1 - \sigma_\omega)}{\pi} \int_0^{2\pi} \int_{-1}^0 g_\omega^-(0, \mu', \phi') \mu' d\mu' d\phi' \right), \quad (2)$$

for $\mu \in [-1, 0)$,

$$g_\omega^-(d, \mu, \phi) = p_\omega g_\omega^+(d, -\mu, \phi) + (1 - p_\omega) \left(\sigma_\omega \frac{C_\omega \Delta T(z=d)}{4\pi} + \frac{(1 - \sigma_\omega)}{\pi} \int_0^{2\pi} \int_0^1 g_\omega^+(d, \mu', \phi') \mu' d\mu' d\phi' \right),$$

where d is the thickness in the cross-plane direction, $g_\omega^+(0, \mu, \phi)$ is the phonon distribution leaving the cross-plane wall at $z = 0$, $g_\omega^-(0, \mu, \phi)$ is the phonon distribution approaching the cross-plane wall at $z = 0$, $g_\omega^+(d, \mu, \phi)$ is the phonon distribution approaching the cross-plane wall at $z = d$, $g_\omega^-(d, \mu, \phi)$ is the phonon distribution leaving the cross-plane wall at $z = d$, C_ω is the specific heat of a phonon mode with frequency ω , and p_ω and σ_ω are the phonon specularity parameter and the thermalization parameter for the thin film walls, respectively. The specularity parameter represents the fraction of specularly scattered phonons at the thin film walls and the thermalization parameter represents the fraction of the phonon distribution that is absorbed and reemitted at the local equilibrium temperature of the thin film walls. For simplicity, we ignore mode conversion for nonthermalizing boundary condition in our analysis. The simulation domain and the boundary conditions [Eq. (2)] are pictorially represented in Fig. 1.

The unknown quantities in this problem are the phonon distribution function [$g_\omega(t, x, z, \mu, \phi)$] and the deviational temperature distribution [$\Delta T(t, x, z)$]. They are related to each other through the energy conservation requirement,

$$\int_{\omega=0}^{\omega_m} \int_{\mu=-1}^1 \int_{\phi=0}^{2\pi} \left[\frac{g_\omega}{\tau_\omega} - \frac{1}{4\pi} \frac{C_\omega}{\tau_\omega} \Delta T \right] d\phi d\mu d\omega = 0. \quad (3)$$

Due to the high dimensionality of the BTE, analytical or semianalytical solutions are only available in the literature for either semi-infinite domains [23–25] or domains with simple boundary and transport conditions [26] or with several approximations [27]. For nanostructures with physically realistic boundaries, several numerical solutions of the BTE have been reported [11, 16, 28]. However, computationally efficient analytical or semianalytical solutions for the in-plane heat conduction along even simple unpatterned films [10, 20] are unavailable. To overcome this problem, we solve the BTE analytically for steady state transport (Sec. II B) and semianalytically for transient transport along thin films in the transient grating (TG) experiment [10, 20] (Sec. II C).

B. Steady state heat conduction in thin films

In this section, we extend the Fuchs-Sondheimer relation for thermal conductivity suppression due to phonon boundary scattering to the general boundary conditions described in Eq. (2). To simulate steady state transport, Q_ω is set to 0 in the BTE [Eq. (1)]. Furthermore, we assume that a one-dimensional

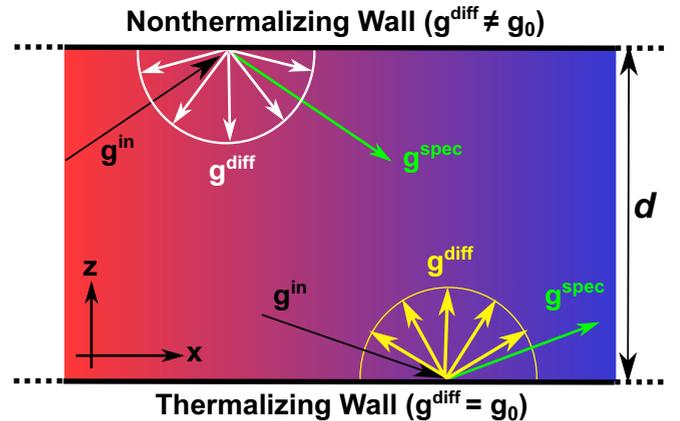


FIG. 1. Spatial distribution of the temperature profile and pictorial representation of the boundary conditions [Eq. (2)] used in this work. The thin film is assumed to be infinite in extent along the in-plane (x) direction and has a finite thickness (d) in the cross-plane (z) direction. For steady state transport calculations, the temperature gradient exists only in the in-plane (x) direction. For transient transport, the initial temperature distribution is an in-plane sinusoidal distribution with a period λ , but can develop a cross-plane temperature gradient at later times. In the case of the nonthermalizing wall, the diffusely reflected component [g^{diff}] of the distribution function is isotropic but away from local thermal equilibrium at the boundary while for the thermalizing wall, [g^{diff}] is equal to the local equilibrium distribution function [g_0]. For both thermalizing and nonthermalizing boundary conditions, the specular reflection component [g^{spec}] has its direction reversed compared to the incoming distribution [g^{in}] and is also away from the local thermal equilibrium. In our work, we consider either thermalizing or nonthermalizing boundary conditions for both walls of the thin films at a time.

temperature gradient exists along the thin film (Fig. 1) and $\frac{\partial g_\omega}{\partial x} \approx \frac{\partial g_\omega^0}{\partial x}$. These assumptions are consistent with the conditions under which typical steady state thermal transport measurements are conducted on nanostructures [19,29,30]. Under these assumptions, the BTE is simplified as

$$v_\omega \mu \frac{\partial g_\omega}{\partial z} + v_\omega \sqrt{1 - \mu^2} \cos \phi \frac{\partial g_\omega^0}{\partial x} = -\frac{g_\omega - g_\omega^0}{\tau_\omega}. \quad (4)$$

for $\mu \in (0, 1]$,

$$\bar{g}_\omega^+(0, \mu, \phi) = p_\omega \bar{g}_\omega^-(0, -\mu, \phi) - \frac{(1 - p_\omega)(1 - \sigma_\omega)}{\pi} \int_0^{2\pi} \int_{-1}^0 \bar{g}_\omega^-(0, \mu', \phi') \mu' d\mu' d\phi', \quad (6)$$

for $\mu \in [-1, 0)$,

$$\bar{g}_\omega^-(d, \mu, \phi) = p_\omega \bar{g}_\omega^+(d, -\mu, \phi) + \frac{(1 - p_\omega)(1 - \sigma_\omega)}{\pi} \int_0^{2\pi} \int_0^1 \bar{g}_\omega^+(d, \mu', \phi') \mu' d\mu' d\phi'.$$

The general solution of the BTE [Eq. (5)] along with the boundary conditions [Eq. (6)] is given by

$$\begin{aligned} \bar{g}_\omega^+(z, \mu, \phi) &= -\Lambda_\omega \cos \phi \sqrt{1 - \mu^2} \frac{\partial g_\omega^0}{\partial x} \left[1 - \frac{\exp\left(-\frac{z}{\mu\Lambda_\omega}\right)(1 - p_\omega)}{1 - p_\omega \exp\left(-\frac{d}{\mu\Lambda_\omega}\right)} \right] \\ &\quad + \underbrace{\frac{(1 - p_\omega)(1 - \sigma_\omega) [A_\omega^+ + p_\omega \exp\left(-\frac{d}{\mu\Lambda_\omega}\right) A_\omega^-]}{1 - p_\omega^2 \exp\left(-\frac{2d}{\mu\Lambda_\omega}\right)}}_I \exp\left(-\frac{z}{\mu\Lambda_\omega}\right), \\ \bar{g}_\omega^-(z, -\mu, \phi) &= -\Lambda_\omega \cos \phi \sqrt{1 - \mu^2} \frac{\partial g_\omega^0}{\partial x} \left[1 - \frac{\exp\left(-\frac{(d-z)}{\mu\Lambda_\omega}\right)(1 - p_\omega)}{1 - p_\omega \exp\left(-\frac{d}{\mu\Lambda_\omega}\right)} \right] \\ &\quad + \underbrace{\frac{(1 - p_\omega)(1 - \sigma_\omega) [A_\omega^- + p_\omega \exp\left(-\frac{d}{\mu\Lambda_\omega}\right) A_\omega^+]}{1 - p_\omega^2 \exp\left(-\frac{2d}{\mu\Lambda_\omega}\right)}}_{II} \exp\left(-\frac{(d-z)}{\mu\Lambda_\omega}\right) \end{aligned} \quad (7)$$

for $\mu \in (0, 1]$. Here, the terms A_ω^+ and A_ω^- only depend on phonon frequency. In particular, they are independent of the angular coordinates μ and ϕ . The derivation of the final expressions for $\bar{g}_\omega^+(z, \mu, \phi)$ and $\bar{g}_\omega^-(z, -\mu, \phi)$ [Eq. (7)] is shown in Sec. I of the Supplemental Material [31]. The expression for the in-plane (x direction) spectral heat flux is given by

$$\begin{aligned} q_{x,\omega} &= \frac{1}{d} \int_{z=0}^d \int_{\mu=-1}^1 \int_{\phi=0}^{2\pi} v_x \bar{g}_\omega \frac{D(\omega)}{4\pi} d\phi d\mu dz \\ &= -\left[\frac{1}{3} C_\omega v_\omega \Lambda_\omega \right] \frac{\partial T}{\partial x} \left[1 - \frac{3(1 - p_\omega)\Lambda_\omega}{2d} \int_0^1 (\mu - \mu^3) \frac{1 - \exp\left(-\frac{d}{\mu\Lambda_\omega}\right)}{1 - p_\omega \exp\left(-\frac{d}{\mu\Lambda_\omega}\right)} d\mu \right] \end{aligned} \quad (8)$$

since the diffuse contributions to the distribution functions $\bar{g}_\omega^+(z, \mu, \phi)$ and $\bar{g}_\omega^-(z, -\mu, \phi)$ [terms I and II in Eq. (7)] are independent of the azimuthal angle ϕ and integrate out to 0. Comparing Eq. (8) with the expression for heat flux from the Fourier's law, the spectral effective thermal conductivity of the thin film is obtained as a product of the bulk spectral thermal conductivity and the well-known Fuchs-Sondheimer reduction factor due to phonon boundary scattering given by

$$k_{\omega,\text{eff}}(d) = \underbrace{\left[\frac{1}{3} C_\omega v_\omega \Lambda_\omega \right]}_{k_{\omega,\text{bulk}}} \underbrace{\left[1 - \frac{3(1 - p_\omega)\Lambda_\omega}{2d} \int_0^1 (\mu - \mu^3) \frac{1 - \exp\left(-\frac{d}{\mu\Lambda_\omega}\right)}{1 - p_\omega \exp\left(-\frac{d}{\mu\Lambda_\omega}\right)} d\mu \right]}_{\text{Fuchs-Sondheimer reduction factor } F\left(\frac{\Lambda_\omega}{d}\right)}. \quad (9)$$

It is interesting to observe from Eq. (9) that the spectral effective thermal conductivity is independent of the thermalization parameter σ_ω even though a general boundary condition [Eq. (2)] has been used in this derivation. Thus, the steady state thermal conductivity suppression due to boundary scattering is only influenced by the relative extent of specular and diffuse scattering (parametrized by the specularity parameter p_ω) and does not depend on the type of diffuse scattering process (parametrized by the thermalization parameter σ_ω). We explicitly demonstrate this result using numerical simulations in Sec. III A.

C. Transient heat conduction in thin films

In this section, we solve the BTE [Eq. (1)] for transient thermal transport along a thin film. The initial temperature profile considered in this work is identical to that of the TG experiment, which has been used extensively to study heat conduction in suspended thin films [10,20]. In the TG experiment, the thermal transport properties of the sample are obtained by observing the transient decay of a one-dimensional impulsive sinusoidal temperature grating on the sample at different grating periods. In the large grating period limit of heat diffusion, the temporal decay is a single exponential. Since the initial temperature distribution is an infinite one-dimensional sinusoid in the x direction, the temperature distribution remains spatially sinusoidal at all later times. Therefore, each wave vector q in the spatially Fourier transformed BTE directly corresponds to a unique grating period $\lambda = 2\pi/q$. Unlike in the steady state case, here we solve for the absolute phonon distribution g_ω rather than the deviation $\bar{g}_\omega = g_\omega - g_\omega^0$. Furthermore, the BTE is solved in the frequency domain (η) by Fourier transforming Eq. (1) in the time variable t . With these transformations, the BTE reduces to

$$i\eta G_\omega + \mu v_\omega \frac{\partial G_\omega}{\partial z} + iq v_\omega \sqrt{1 - \mu^2} \cos \phi G_\omega = -\frac{G_\omega}{\tau_\omega} + \frac{1}{4\pi} \frac{C_\omega}{\tau_\omega} \Delta \bar{T} + \frac{\bar{Q}_\omega}{4\pi}, \quad (10)$$

where the substitution $G_0(T) = \frac{1}{4\pi} C_\omega \Delta \bar{T}$ has been made and G_ω represents the spatial (in-plane axis) and temporal Fourier transform of absolute phonon energy distribution function g_ω .

The outline of the solution methodology for Eq. (10) is as follows. The general solution is given by

$$\begin{aligned} \text{for } \mu \in (0, 1], \quad G_\omega^+(z, \mu, \phi) &= G_\omega^+(0, \mu, \phi) \exp\left(-\frac{\gamma_{\mu\phi}^{\text{FS}}}{\mu \Lambda_\omega} z\right) + \frac{\exp\left(-\frac{\gamma_{\mu\phi}^{\text{FS}}}{\mu \Lambda_\omega} z\right)}{4\pi \mu \Lambda_\omega} \int_0^z (C_\omega \Delta \bar{T} + \bar{Q}_\omega \tau_\omega) \exp\left(\frac{\gamma_{\mu\phi}^{\text{FS}}}{\mu \Lambda_\omega} z'\right) dz', \\ \text{for } \mu \in [-1, 0), \quad G_\omega^-(z, \mu, \phi) &= G_\omega^-(d, \mu, \phi) \exp\left(\frac{\gamma_{\mu\phi}^{\text{FS}}}{\mu \Lambda_\omega} (d - z)\right) - \frac{\exp\left(-\frac{\gamma_{\mu\phi}^{\text{FS}}}{\mu \Lambda_\omega} z\right)}{4\pi \mu \Lambda_\omega} \int_z^d (C_\omega \Delta \bar{T} + \bar{Q}_\omega \tau_\omega) \exp\left(\frac{\gamma_{\mu\phi}^{\text{FS}}}{\mu \Lambda_\omega} z'\right) dz', \end{aligned}$$

where $\gamma_{\mu\phi}^{\text{FS}} = (1 + i\eta\tau_\omega) + i\Lambda_\omega q \sqrt{1 - \mu^2} \cos \phi$. (11)

Here, $G_\omega^+(0, \mu, \phi)$ and $G_\omega^-(d, \mu, \phi)$ are determined by solving the boundary conditions [Eq. (2)] with the following procedure. First, the angular integrals in the boundary conditions are discretized using Gauss quadrature with weights w_{μ_i} and w_{ϕ_j} for the variables μ and ϕ respectively, which results in the following set of linear equations in the variables $G_\omega^+(0, \mu_i, \phi_j)$ and $G_\omega^-(d, -\mu_i, \phi_j)$ for every $\{\mu_i, \phi_j\} \in (0, 1] \times [0, 2\pi]$ doublet from the discretization:

$$\begin{aligned} G_\omega^+(0, \mu_i, \phi_j) &= p_\omega G_\omega^-(d, -\mu_i, \phi_j) \exp\left(-\frac{\gamma_{ij}^{\text{FS}}}{\mu_i \Lambda_\omega} d\right) + \frac{p_\omega}{4\pi \mu_i \Lambda_\omega} \int_0^d (C_\omega \Delta \bar{T} + \bar{Q}_\omega \tau_\omega) \exp\left(-\frac{\gamma_{ij}^{\text{FS}}}{\mu_i \Lambda_\omega} z'\right) dz' \\ &+ (1 - p_\omega) \left[\sigma_\omega \frac{C_\omega \Delta \bar{T}(z=0)}{4\pi} + \frac{(1 - \sigma_\omega)}{\pi} \sum_{i'j'} G_\omega^-(d, -\mu_{i'}, \phi_{j'}) \exp\left(-\frac{\gamma_{i'j'}^{\text{FS}}}{\mu_{i'} \Lambda_\omega} d\right) \mu_{i'} w_{\mu_{i'}} w_{\phi_{j'}} \right. \\ &\left. + \frac{(1 - \sigma_\omega)}{4\pi^2 \Lambda_\omega} \sum_{i'j'} \int_0^d (C_\omega \Delta \bar{T} + \bar{Q}_\omega \tau_\omega) \exp\left(-\frac{\gamma_{i'j'}^{\text{FS}}}{\mu_{i'} \Lambda_\omega} z'\right) dz' w_{\mu_{i'}} w_{\phi_{j'}} \right], \\ G_\omega^-(d, -\mu_i, \phi_j) &= p_\omega G_\omega^+(0, \mu_i, \phi_j) \exp\left(-\frac{\gamma_{ij}^{\text{FS}}}{\mu_i \Lambda_\omega} d\right) + \frac{p_\omega}{4\pi \mu_i \Lambda_\omega} \int_0^d (C_\omega \Delta \bar{T} + \bar{Q}_\omega \tau_\omega) \exp\left(-\frac{\gamma_{ij}^{\text{FS}}}{\mu_i \Lambda_\omega} (d - z')\right) dz' \\ &+ (1 - p_\omega) \left[\sigma_\omega \frac{C_\omega \Delta \bar{T}(z=d)}{4\pi} + \frac{(1 - \sigma_\omega)}{\pi} \sum_{i'j'} G_\omega^+(0, \mu_{i'}, \phi_{j'}) \exp\left(-\frac{\gamma_{i'j'}^{\text{FS}}}{\mu_{i'} \Lambda_\omega} d\right) \mu_{i'} w_{\mu_{i'}} w_{\phi_{j'}} \right. \\ &\left. + \frac{(1 - \sigma_\omega)}{4\pi^2 \Lambda_\omega} \sum_{i'j'} \int_0^d (C_\omega \Delta \bar{T} + \bar{Q}_\omega \tau_\omega) \exp\left(-\frac{\gamma_{i'j'}^{\text{FS}}}{\mu_{i'} \Lambda_\omega} (d - z')\right) dz' w_{\mu_{i'}} w_{\phi_{j'}} \right]. \end{aligned} \quad (12)$$

To obtain Eq. (12), we have substituted the general BTE solution into the boundary conditions to eliminate $G_\omega^-(0, \mu, \phi)$ and $G_\omega^+(d, \mu, \phi)$. Therefore, the only unknowns in the set of linear equations [Eq. (12)] are $G_\omega^+(0, \mu, \phi)$ and $G_\omega^-(d, \mu, \phi)$. By bringing the terms containing $G_\omega^+(0, \mu, \phi)$ and $G_\omega^-(d, \mu, \phi)$ to the left-hand side, Eq. (12) can be written in a concise matrix form:

$$\begin{bmatrix} U_{kk'}^+ & U_{kk'}^- \\ D_{kk'}^+ & D_{kk'}^- \end{bmatrix} \begin{pmatrix} G_\omega^+(0, \mu_i, \phi_j) \\ G_\omega^-(d, -\mu_i, \phi_j) \end{pmatrix} = \begin{pmatrix} \bar{c}_\omega^+(0, \mu_i, \phi_j) \\ \bar{c}_\omega^-(d, \mu_i, \phi_j) \end{pmatrix}, \quad (13)$$

where, $\bar{c}_\omega^+(0, \mu_i, \phi_j)$ and $\bar{c}_\omega^-(d, \mu_i, \phi_j)$ are analytical functions of the unknown temperature distribution function $\Delta\bar{T}$ obtained from the right-hand side of Eq. (12). The solution to this set of linear equations can be represented as

$$\begin{pmatrix} G_\omega^+(0, \mu_i, \phi_j) \\ G_\omega^-(d, -\mu_i, \phi_j) \end{pmatrix} = \begin{bmatrix} T_{kk'}^+ & T_{kk'}^- \\ B_{kk'}^+ & B_{kk'}^- \end{bmatrix} \begin{pmatrix} \bar{c}_\omega^+(0, \mu_i, \phi_j) \\ \bar{c}_\omega^-(d, \mu_i, \phi_j) \end{pmatrix}, \quad (14)$$

where k is the index which represents the doublet $\{\mu_i, \phi_j\}$. The details of the simplification of the boundary conditions and the evaluation of $T_{kk'}^+, T_{kk'}^-, B_{kk'}^+, B_{kk'}^-, \bar{c}_\omega^+(0, \mu_i, \phi_j)$, and $\bar{c}_\omega^-(d, \mu_i, \phi_j)$ are described in Sec. II A of the Supplemental Material [31]. To close the problem, the expressions for $G_\omega^+(z, \mu, \phi)$ and $G_\omega^-(z, \mu, \phi)$ [Eq. (11)] and the boundary conditions [Eq. (14)] are substituted into the energy conservation equation [Eq. (3)] and an integral equation in the variable z for $\Delta\bar{T}(z)$ at each η and q is obtained, which has the form

$$\Delta\bar{T}(z) = h(z) + f(z) + \int_0^d [K(z', z)\Delta\bar{T}(z')]dz', \quad (15)$$

where the functional form of the inhomogeneous parts $f(z)$, $h(z)$ and the kernel $K(z', z)$ are described in Sec. II B of the Supplemental Material [31]. This integral equation [Eq. (15)] is then solved using the method of degenerate kernels for each η and q to obtain the frequency domain solution $\Delta\bar{T}(z)$ for every η and q . The details of the degenerate kernel calculations are described in Sec. II C of the Supplemental Material [31]. Finally, the solution $\Delta\bar{T}(z)$ is substituted into Eq. (11) to obtain expressions for $G_\omega(z, \mu, \phi)$ and also the thickness-averaged in-plane heat flux $j_{x,\omega}$ given by

$$\begin{aligned} j_{x,\omega} &= \frac{1}{4\pi d} \int_0^d \int_0^{2\pi} \int_{-1}^1 G_\omega v_\omega \sqrt{1-\mu^2} \cos \phi d\mu d\phi dz \\ &= \frac{1}{4\pi} \sum_{ij} \left(\frac{\mu_i \text{Kn}_\omega^d}{\gamma_{ij}^{\text{FS}}} \sum_{i'j'} [(T_{kk'}^+ + B_{kk'}^+) \bar{c}_\omega^+(0, \mu_{i'}, \phi_{j'}) + (T_{kk'}^- + B_{kk'}^-) \bar{c}_\omega^-(d, \mu_{i'}, \phi_{j'})] \left[1 - \exp\left(-\frac{\gamma_{ij}^{\text{FS}}}{\mu_i \text{Kn}_\omega^d}\right) \right] \right. \\ &\quad \left. + \frac{2}{4\pi \gamma_{ij}^{\text{FS}}} \left(C_\omega \frac{t_0}{2} + \bar{Q}_\omega \tau_\omega \right) \left\{ 1 - \frac{\mu_i \text{Kn}_\omega^d}{\gamma_{ij}^{\text{FS}}} \left[1 - \exp\left(-\frac{\gamma_{ij}^{\text{FS}}}{\mu_i \text{Kn}_\omega^d}\right) \right] \right\} \right. \\ &\quad \left. - \frac{C_\omega \left[1 - \exp\left(-\frac{\gamma_{ij}^{\text{FS}}}{\mu_i \text{Kn}_\omega^d}\right) \right]}{4\pi \mu_i \text{Kn}_\omega^d} \sum_{m=1}^N t_m \frac{1 + (-1)^m}{m^2 \pi^2 + \left(\frac{\gamma_{ij}^{\text{FS}}}{\mu_i \text{Kn}_\omega^d}\right)^2} \right) v_\omega \sqrt{1-\mu_i^2} w_{\mu_i} w_{\phi_j}, \end{aligned} \quad (16)$$

where the t_i 's are the Fourier coefficients for the expansion of $\Delta\bar{T}$ in the cross-plane (z) direction and $\text{Kn}_\omega^d = \Lambda_\omega/d$ is the Knudsen number. The conventional approach to describe the thermal transport properties of the thin film is to compare the expression for heat flux from the BTE solution with that expected for heat diffusion, as was done in Eq. (8) for the steady state Fuchs-Sondheimer theory. However, in practice, Eq. (16) is not easily reduced into the form of Fourier's law. To overcome this problem, we adopt the following strategy. The solution of the Fourier heat equation to a one-dimensional heat conduction with an instantaneous spatially sinusoidal heat source is a simple exponential decay $\Delta T(t, x=0) = \Delta T_0 \exp(-\gamma t)$, where the decay rate (γ) is related to the effective thermal conductivity (k_{eff}) and the volumetric heat capacity of the solid (C) as $\gamma = k_{\text{eff}} q^2 / C$. Therefore, to obtain the effective thermal conductivity from our calculations, we perform an inverse Fourier transform of the temperature distribution averaged in the z direction $[\int_0^d \Delta\bar{T}(\eta, q, z) dz]$ with respect to the variable η , fit the resulting solution to an exponentially decaying function $\Delta T_0 \exp(-\gamma t)$, and extract the thermal conductivity from the fit. If the fitting fails, the transport is in the strongly quasiballistic regime [25] and we conclude that the Fourier law description of the heat

conduction with an effective thermal conductivity k_{eff} is not valid for that case.

The semianalytical solution of the BTE for transient transport presented in this work is computationally very efficient, taking only a few seconds on a single computer processor, while the direct Monte Carlo simulation of the BTE takes up to a few days on a high-performance computer cluster executed in parallel mode. Moreover, it is computationally challenging to extract the heat flux distribution directly from the Monte Carlo solution, while in our semianalytical solution, the evaluation of heat flux distribution is a single step process [Eq. (16)].

III. RESULTS AND DISCUSSION

We now present the results of the calculations for free-standing silicon thin films. To obtain these results, we use an isotropic dispersion and intrinsic scattering rates calculated using a Gaussian kernel-based regression [32] from the *ab initio* phonon properties of isotopically pure silicon. The first-principles phonon properties are calculated by Carrete and Mingo using ShengBTE [33,34] and Phonopy [35] from the interatomic force constants calculated using VASP [36–39].

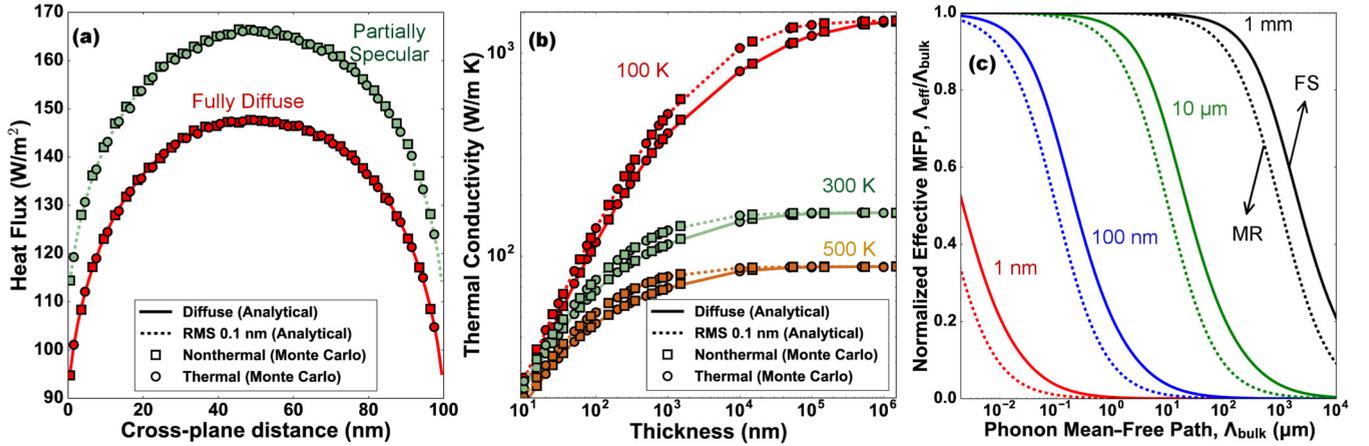


FIG. 2. (a) Comparison of the cross-plane distribution of the in-plane steady state heat flux between analytical and Monte Carlo solutions of the BTE at 300 K and film thickness of 100 nm for different boundary conditions. The geometry of the thin film and the coordinate axes used in this work are shown in the inset. (b) Comparison of the steady state thermal conductivity between analytical and Monte Carlo solutions of the BTE at different temperatures and thin film thicknesses. For both (a) and (b), the Monte Carlo solutions are identical for thermalizing and nonthermalizing boundary scattering and agree well with the analytical solution derived in this work for both fully diffuse and partially specular boundary conditions (RMS 0.1 nm). For the partially specular boundary condition, the specularity parameter (p_ω) is calculated from Ziman’s specularity model [40] for a surface rms roughness of 0.1 nm. (c) Effective MFPs of phonons computed using Matthiessen’s rule (MR) and the Fuchs-Sondheimer (FS) theory for different film thicknesses and fully diffuse boundary scattering. Matthiessen’s rule underpredicts the effective phonon MFPs in thin films compared to the Fuchs-Sondheimer theory, which is a rigorous BTE solution.

A. Steady state transport in thin films

1. Comparison with Monte Carlo solution

We first examine steady state heat condition along thin films. Figures 2(a) and 2(b) show the cross-plane distribution of the in-plane heat flux and the effective thermal conductivity, respectively, for steady state transport through thin films computed using a Monte Carlo technique and the analytical solution from this work. The details of the Monte Carlo technique used in this work are described in Sec. III of the Supplemental Material [31]. For both fully diffuse and partially specular boundary conditions, the heat flux distribution and the effective thermal conductivity of the thin film show excellent agreement between the Monte Carlo solutions and the analytical solution from this work over a range of temperatures and film thicknesses. In particular, both solutions predict identical heat flux and thermal conductivities for thermalizing and nonthermalizing boundary conditions at the thin film walls since the steady state transport is insensitive to the type of diffuse boundary scattering of phonons, as discussed in Sec. II B. This observation can be generalized further to state that in steady state thermal transport experiments on thin films, it is impossible to distinguish between nonthermalizing and *any* type of inelastic diffuse scattering of phonons at boundaries.

2. Effective phonon mean-free path

We also examine the effective mean-free path (MFP) of phonons within the thin film for various film thicknesses. An approach to estimate the effective phonon mean-free path in thin films is by using Matthiessen’s rule [40] given by

$$\frac{1}{\Lambda_{\omega,\text{eff}}} = \frac{1}{\Lambda_{\omega,\text{bulk}}} + \frac{1 - p_\omega}{1 + p_\omega} \frac{1}{d}, \quad (17)$$

where d is the thickness of the thin film and $\Lambda_{\omega,\text{bulk}}$ is the intrinsic phonon mean-free path in the bulk material. Although Matthiessen’s rule has been used in the past for computational [41] and experimental [42] investigations of phonon boundary scattering, the mathematical rigor of such an expression for the effective mean-free path is unclear. On the other hand, the effective mean-free path of phonons in thin films can also be determined rigorously from the Fuchs-Sondheimer factor [$F(\Lambda_\omega/d)$], since by definition, $F(\Lambda_\omega/d) = k_{\omega,\text{eff}}/k_{\omega,\text{bulk}} = \Lambda_{\omega,\text{eff}}/\Lambda_{\omega,\text{bulk}}$. Figure 2(c) shows the comparison of the normalized effective phonon mean-free paths obtained from the Fuchs-Sondheimer factor and Matthiessen’s rule for different film thicknesses. Matthiessen’s rule underpredicts phonon MFPs comparable to the thickness of the film. Even for phonons with intrinsic mean-free path an order of magnitude smaller than the film thickness, Matthiessen’s rule predicts a shorter effective phonon mean-free path compared to the predictions of the Fuchs-Sondheimer factor from the rigorous solution of the BTE, which is consistent with the findings of another work based on Monte Carlo sampling [43]. This result highlights the importance of using the rigorous BTE solution to estimate the extent of diffuse phonon boundary scattering even in simple nanostructures.

B. Transient transport in thin films

We now examine transient thermal conduction along thin films observed in the TG experiment. To perform this calculation, we solve the integral equation [Eq. (15)] semianalytically using the same isotropic phonon properties used in steady state transport calculations. The source term in the BTE [Eq. (10)] is assumed to follow a thermal distribution given by $Q_\omega = C_\omega \Delta T_0$, where C_ω is the volumetric specific heat of the phonon mode.

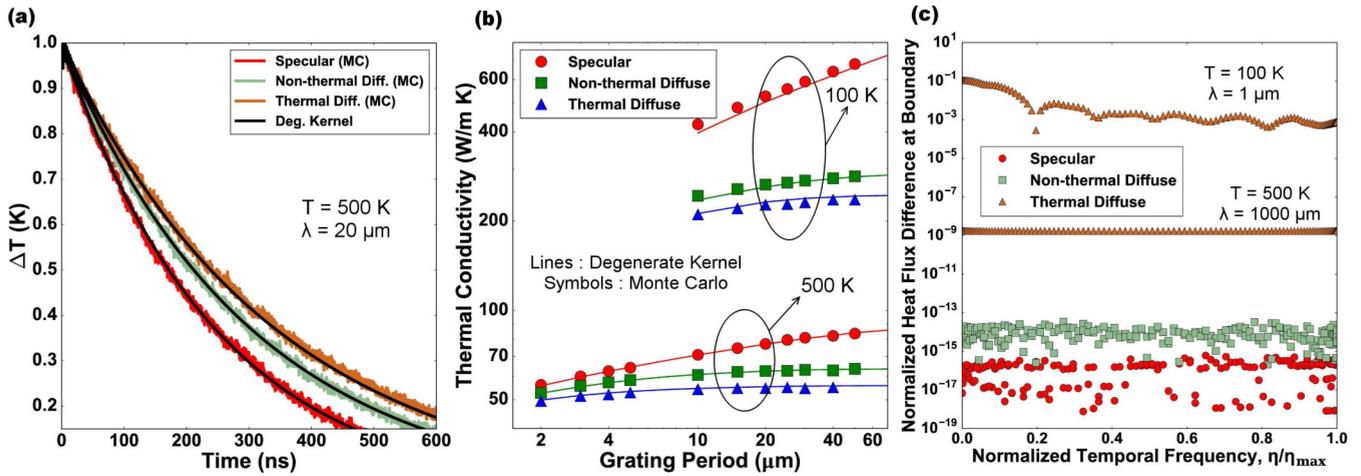


FIG. 3. (a) Comparison between time traces from the Monte Carlo (colored noisy lines) and the degenerate kernels solutions (black lines) of the BTE for a grating period of 20 μm at 500 K. (b) Comparison of the thermal conductivity predictions from the Monte Carlo (symbols) and the degenerate kernels solutions (black lines) of the BTE for different temperatures and grating periods. For both (a) and (b), the Monte Carlo solutions and the BTE solutions from this work are in very good agreement. (c) Plot showing the difference between the incoming and outgoing heat flux normalized by the incoming heat flux at the thin film boundaries as a function of the temporal frequency normalized by the maximum temporal frequency at which the simulations were performed (η_{max}). Specular and nonthermalizing diffuse boundary conditions conserve heat flux to numerical precision while the thermalizing diffuse boundary condition violates heat flux conservation at the film wall under quasiballistic ($T = 100$ K, grating period = 1 μm) and diffusive ($T = 500$ K, grating period = 1000 μm) transport regimes.

1. Difference between thermalizing and nonthermalizing boundary scattering

Figure 3(a) shows a comparison of the time traces calculated from the degenerate kernel method and the Monte Carlo method for a grating period of 20 μm . To obtain the thickness averaged time traces using the degenerate kernels method, we used 6 Gauss quadrature points for the μ variable, 10 Gauss quadrature points for the ϕ variable, and 1 term in the Fourier cosine expansion to achieve a convergence threshold of 10^{-6} on the relative change in the solution for an increase in the number of discretization points. The transient decays are in good agreement between the degenerate kernel and the Monte Carlo solutions over a wide range of temperatures and different boundary conditions. As expected, the solution for the specular boundary condition results in a faster transient decay than the diffuse boundary conditions since a specularly reflecting wall does not resist the flow of heat in the in-plane direction. However, the transient decay for the nonthermalizing diffuse boundary condition is faster than the thermalizing diffuse boundary condition, indicating that the thermalizing boundary condition offers higher resistance to heat flow than the nonthermalizing diffuse scattering.

This observation is also evident from Fig. 3(b) which shows the thermal conductivities obtained by fitting the time traces to an exponential decay for different temperatures, different grating periods, and different boundary conditions. The observed thermal conductivity of the thin film decreases with decreasing grating period due to the breakdown of Fourier's law of heat conduction and the onset of quasiballistic thermal transport [25] when the grating period is comparable to phonon MFPs. Consistent with the findings from the time traces, the thermal conductivity of the thin film with specular walls is higher than that of the thin film with diffuse walls. Moreover, even for very long grating periods compared to phonon MFPs, where the thermal transport is diffusive and

obeys Fourier's law, the thermal conductivity of thin film with nonthermalizing diffuse walls is higher than that of the thin films with thermalizing diffuse walls. This observation is in stark contrast with the steady state condition, where there was no difference in thermal conductivity between thermalizing and nonthermalizing boundary conditions.

2. Validity of the thermalizing and nonthermalizing boundary conditions

At this point, it is important to investigate the validity of the thermalizing and nonthermalizing boundary condition for the thin film walls. The nonthermalizing boundary scattering condition can be naturally derived from the conservation of heat flux at the boundary [27]. However, the thermalizing boundary condition is not derived from the heat flux conservation at the boundary. Therefore, in the absence of any external scattering mechanisms, phonons cannot reach the local thermal equilibrium and simultaneously conserve heat flux at the boundary in general, because of the following reason.

Consider a boundary at $z = 0$ separating a solid at $z > 0$ from vacuum in $z < 0$. The incoming phonon distribution at $z = 0$ is $g_{\omega}^{-}(0, \mu, \phi)$, which is a general phonon distribution, not necessarily at the local thermal equilibrium. According to the formulation of the thermalizing diffuse boundary condition, the outgoing phonon distribution, in the case of fully diffuse boundary scattering, is given by $g_{\omega}(\Delta T(z = 0)) \approx \frac{C_{\omega}}{4\pi} \Delta T(z = 0)$, where C_{ω} is the heat capacity of the phonon mode and $\Delta T(z = 0)$ is the local equilibrium temperature at the boundary $z = 0$. Since the boundary separates a solid from vacuum, all of the heat flux incident on the boundary has to be reflected back into the solid. This constraint on the incident and reflected heat flux at the thermalizing diffuse boundary

leads to the following relation for $\Delta T(z = 0)$:

$$\Delta T(z = 0) = 4 \frac{\sum_p \int_{\omega=0}^{\omega_{\max}} \int_{\mu=-1}^0 \int_{\phi=0}^{2\pi} g_{\omega}^{-}(0, \mu, \phi) v_{\omega} \mu d\mu d\phi d\omega}{\sum_p \int_{\omega=0}^{\omega_{\max}} C_{\omega} v_{\omega} d\omega}. \quad (18)$$

Additionally, energy conservation [Eq. (3)] has to be satisfied at all locations including the boundaries in the absence of any other source or sink of phonons. This requirement further adds constraints on $\Delta T(z = 0)$ through the relation

$$\Delta T(z = 0) = 2 \frac{\sum_p \int_{\omega=0}^{\omega_{\max}} \int_{\mu=-1}^0 \int_{\phi=0}^{2\pi} \frac{g_{\omega}^{-}(0, \mu, \phi)}{\tau_{\omega}} d\mu d\phi d\omega}{\sum_p \int_{\omega=0}^{\omega_{\max}} \frac{C_{\omega}}{\tau_{\omega}} d\omega}. \quad (19)$$

For the assumptions made in the Fuchs-Sondheimer theory under steady state transport conditions, the integrals of the incoming and the outgoing deviational distribution functions [Eq. (7)] over the azimuthal angle ϕ are 0. Therefore, there is no heat flux towards or away from the boundary and the constraints on $\Delta T(z = 0)$ [given by Eqs. (18) and (19)] are trivially satisfied. However, in general, these two expressions for $\Delta T(z = 0)$ are not equal, indicating that phonons cannot thermalize at the boundaries in the absence of any external source or sink of phonons.

Figure 3(c) shows the difference between the incoming and outgoing total heat flux at the thin film wall ($z = 0$) as a function of the temporal frequency η . The specular and nonthermalizing diffuse boundary conditions satisfy heat flux conservation to numerical precision. However, there is a significant difference between the incoming and the outgoing heat flux for the thermalizing diffuse boundary condition under quasiballistic ($T = 100$ K, grating period = $1 \mu\text{m}$) and diffusive ($T = 500$ K, grating period = $1000 \mu\text{m}$) transport regimes. Nevertheless, it is still possible for inelastic (but not thermalizing) diffuse boundary scattering to take place as long as the following conditions for heat flux are met at the thin film boundaries:

$$\begin{aligned} & \sum_p \int_{\omega=0}^{\omega_{\max}} g_{\omega}^{+}(z = 0) v_{\omega} d\omega \\ &= -\frac{1}{\pi} \sum_p \int_{\omega=0}^{\omega_{\max}} \int_{\mu=-1}^0 \int_{\phi=0}^{2\pi} g_{\omega}^{-}(z = 0, \mu, \phi) v_{\omega} \mu d\mu d\phi d\omega, \\ & \sum_p \int_{\omega=0}^{\omega_{\max}} g_{\omega}^{-}(z = d) v_{\omega} d\omega \\ &= \frac{1}{\pi} \sum_p \int_{\omega=0}^{\omega_{\max}} \int_{\mu=0}^1 \int_{\phi=0}^{2\pi} g_{\omega}^{+}(z = d, \mu, \phi) v_{\omega} \mu d\mu d\phi d\omega. \end{aligned}$$

3. Comparison with Fuchs-Sondheimer theory at different grating periods

We now examine whether the Fuchs-Sondheimer theory can be used to explain transient heat conduction in the TG experiment along thin films. If the suppression in thermal conductivity of thin films due to phonon boundary scattering and quasiballistic effects in the TG experiment are assumed to be independent, Fuchs-Sondheimer theory can be employed

to describe quasiballistic transport in the TG experiment using the following expression:

$$k(q, d) = \sum_p \int_0^{\omega_{\max}} F\left(p_{\omega}, \frac{\Lambda_{\omega}}{d}\right) S(q\Lambda_{\omega}) \left[\frac{1}{3} C_{\omega} v_{\omega} \Lambda_{\omega}\right] d\omega, \quad (20)$$

where $F(p_{\omega}, \frac{\Lambda_{\omega}}{d})$ is the Fuchs-Sondheimer suppression function from the steady state transport condition and $S(q\Lambda_{\omega})$ is the quasiballistic suppression function [25] for a grating period q . Recent works [20] have used a similar expression for the thermal conductivity suppression of the form

$$\begin{aligned} k(q, d) &= \sum_p \int_0^{\omega_{\max}} F\left(p_{\omega}, \frac{\Lambda_{\omega}}{d}\right) S\left(q\Lambda_{\omega} F\left(p_{\omega}, \frac{\Lambda_{\omega}}{d}\right)\right) \\ &\times \left[\frac{1}{3} C_{\omega} v_{\omega} \Lambda_{\omega}\right] d\omega. \end{aligned} \quad (21)$$

Henceforth, Eq. (20) is referred to as FS I and Eq. (21) is referred to as FS II. Figure 4(a) shows the comparison of thermal conductivity obtained by fitting the BTE solution for temperature decay, and thermal conductivities from FS I and FS II models for fully diffuse boundary scattering. We only consider nonthermalizing diffuse scattering as we have shown that thermalizing diffuse scattering is unphysical for the problem considered here. At very long grating periods, when the transport is primarily diffusive, the thermal conductivity predictions from FS I and FS II match well with the BTE solution from this work, as expected. However, at the shorter grating periods comparable to phonon MFPs, where the transport is in the quasiballistic regime, FS I underpredicts the thin film thermal conductivity while FS II overpredicts it.

This observation is also evident from the magnitude of the suppression function plotted at $\eta = 0$ for fully diffuse boundary conditions shown in Figs. 4(b) and 4(c). The suppression function for the thin film geometry is defined as

$$S(q\Lambda_{\omega}, \Lambda_{\omega}/d, \eta\tau_{\omega}, p_{\omega}) = \frac{\kappa_{\omega, \text{BTE}}}{\kappa_{\omega, \text{Fourier}}}, \quad (22)$$

where $\kappa_{\omega} = j_{x, \omega} / \Delta \bar{T}$ is the conductance per phonon mode and $j_{x, \omega}$ is the thickness-averaged in-plane heat flux defined in Eq. (16). In Figs. 4(b) and 4(c), the magnitude of the suppression function at $\eta = 0$ is plotted against the phonon MFP nondimensionalized with respect to the grating period q . The suppression functions from the complete BTE solution and models FS I and FS II are identical at high temperatures and long grating periods, when the transport is primarily diffusive, governed by Fourier's law of heat conduction. However, for low temperatures and short grating periods, FS I underpredicts the heat flux and FS II overpredicts the heat flux carried by phonons with very long MFPs. Moreover, the difference between models FS I and FS II and the BTE solution is smaller for thinner films indicating that enhanced boundary scattering in thinner films delays the onset of quasiballistic heat conduction. These observations emphasize the importance of using the complete BTE solution to accurately investigate boundary scattering when grating periods are comparable to phonon MFPs.

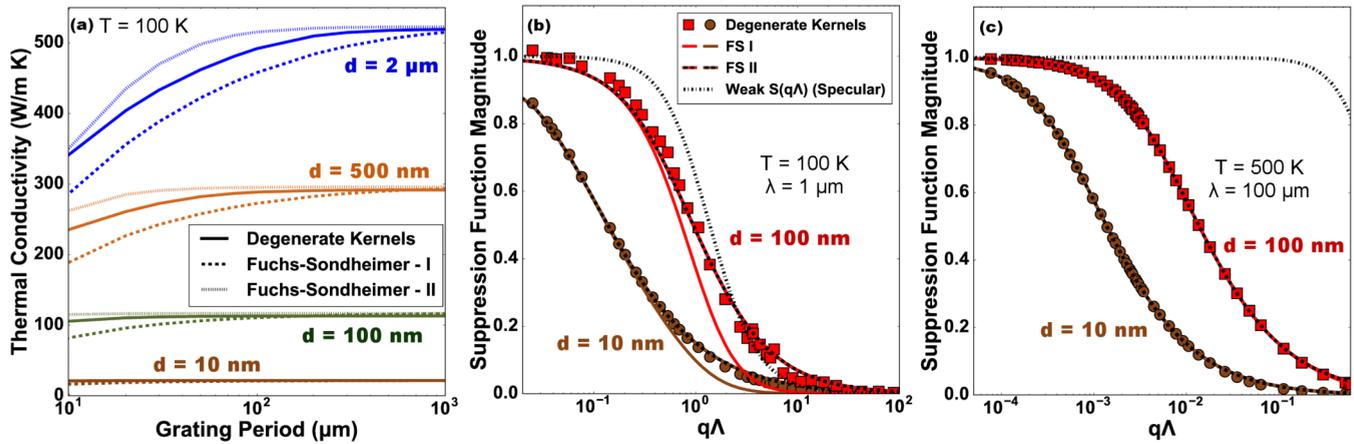


FIG. 4. Comparison of the thermal conductivity (a) and the suppression functions [(b) and (c)] calculated from the models FS I, FS II and by solving the BTE for nonthermalizing diffuse boundary conditions at different temperatures, grating periods (λ), and film thicknesses. In panels (b) and (c), the symbols correspond to the degenerate kernel solution, the solid lines correspond to the FS I model, and the dashed solid lines correspond to the FS II model. For very thin films and long grating periods, the models FS I and FS II are in good agreement with the BTE predictions. For thicker films and shorter grating periods, FS I underpredicts and FS II overpredicts the thermal conductivity at short grating periods (a) and the contribution of phonons with long MFP [(b) and (c)] compared to the complete BTE solution.

IV. CONCLUSION

We have studied the effect of thermalizing and nonthermalizing boundary scattering of phonons in steady state and transient heat conduction along thin films by solving the BTE using analytical and computationally efficient semianalytical techniques. From our analysis, we reach the following conclusions. First, under steady state transport conditions, we find that the thermal transport is governed by the Fuchs-Sondheimer theory and is insensitive to whether the boundaries are thermalizing or not. In contrast, under transient conditions, the decay rates are significantly different for thermalizing and nonthermalizing walls and the Fuchs-Sondheimer theory is only applicable in the heat diffusion regime. We also

show that, for transient transport, the thermalizing wall boundary condition is unphysical due to violation of heat flux conservation. Our results provide insights into the boundary scattering process of thermal phonons over a wide range of heating length scales that are useful for interpreting thermal measurements on nanostructures.

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